

BUK9R4R5-40H

Logic level N-Channel MOSFET in MLPAK56-WF (SOT8038-2)

10 April 2025

Product data sheet

1. General description

Logic level N-Channel MOSFET in a small MLPAK56-WF (SOT8038-2) package, using Trench 9 technology. This product has been designed and qualified to meet AEC-Q101 requirements delivering high performance and reliability.

2. Features and benefits

- Trench 9 technology
- Low $R_{DS(on)}$ to minimize conduction losses
- Small footprint (5 x 6 mm) for compact design
- Qualified to AEC-Q101 at 175 °C
- Side-wettable flanks for robust solder joints and automated optical inspection

3. Applications

- Motor drive
- Battery protection
- DC-DC conversion

4. Quick reference data

Table 1. Quick reference data

Table 1. Quick reference data

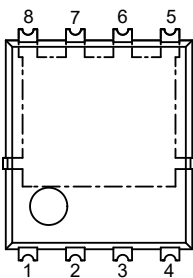
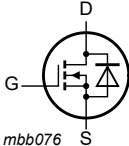
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; Fig. 2		-	-	91	A
P _{tot}	total power dissipation	T _{mb} = 25 °C; Fig. 1		-	-	71	W
T _j	junction temperature			-55	-	175	°C
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11		2.7	3.8	4.5	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 125 °C; Fig. 12		3.9	5.9	7.3	mΩ
Dynamic characteristics							
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; T _j = 25 °C; Fig. 13 ; Fig. 14		-	3.7	7.4	nC
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; T _j = 25 °C; Fig. 13 ; Fig. 14		-	36	50	nC
Avalanche ruggedness							
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I _D = 80 A; V _{sup} ≤ 40 V; R _{GS} = 50 Ω; V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped	[1] [2] [3]	-	-	58	mJ

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Source-drain diode							
Q _r	recovered charge	I _S = 25 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V; V _{DS} = 20 V; T _j = 25 °C; Fig. 17	[4]	-	14	-	nC

- [1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [2] Refer to application note AN10273 for further information.
- [3] Protected by 100% test.
- [4] includes capacitive recovery

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 MLPAK56-WF (SOT8038-2)	 mbb076
2	S	source		
3	S	source		
4	G	gate		
5	D	drain		
6	D	drain		
7	D	drain		
8	D	drain		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUK9R4R5-40H	MLPAK56-WF	MLPAK56-WF: 8 terminals; body 5.15 x 6.2 x 1.0 mm	SOT8038-2

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK9R4R5-40H	94H540R

8. Limiting values

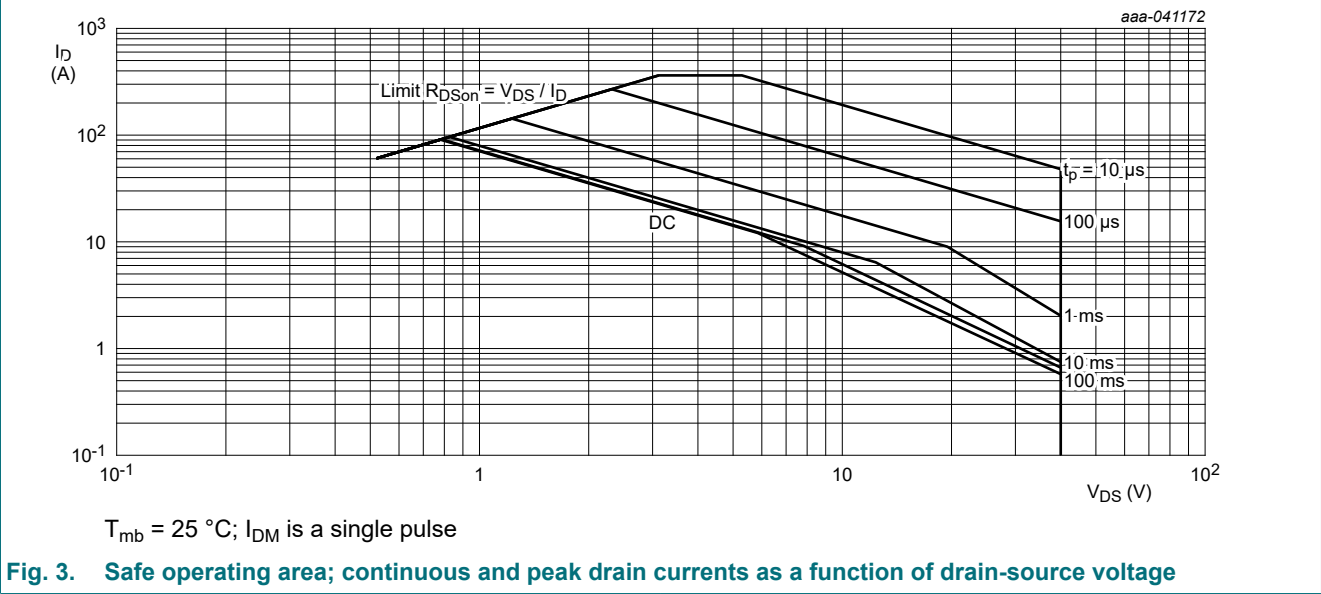
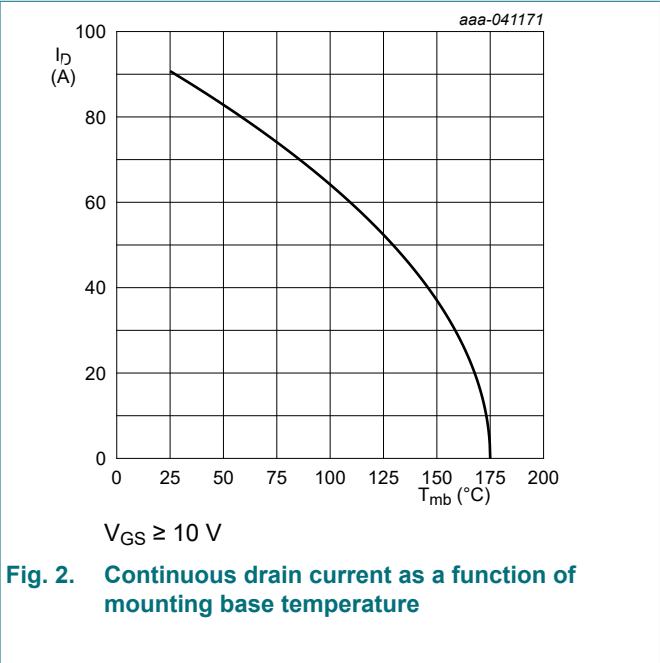
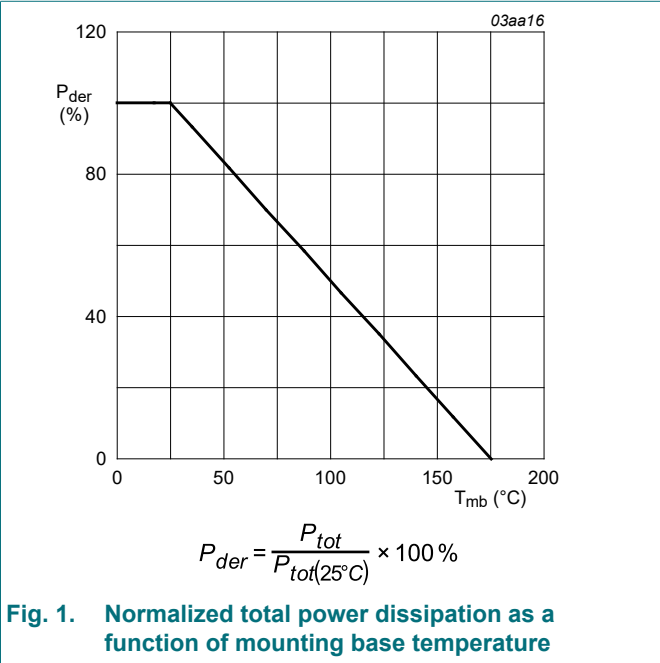
Table 5. Limiting values

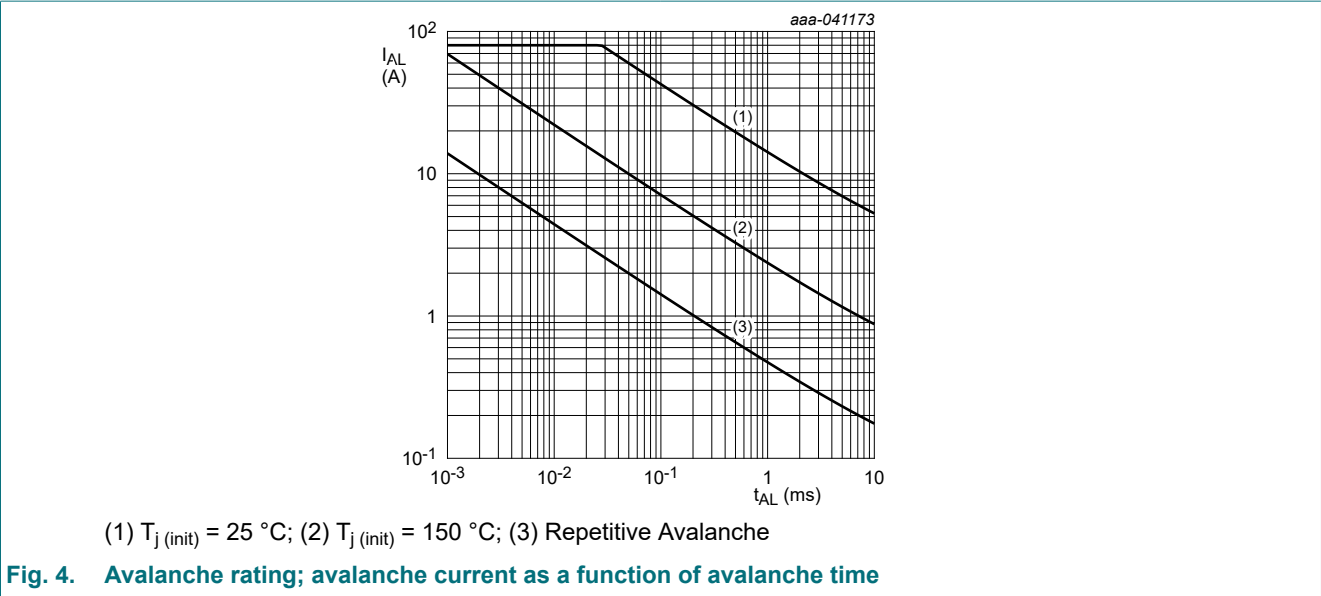
In accordance with the Absolute Maximum Rating System (IEC 60134). T_j = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; Fig. 1		-	71	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; Fig. 2		-	91	A
		V _{GS} = 10 V; T _{mb} = 100 °C		-	64	A
I _{DM}	peak drain current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C; Fig. 3		-	363	A

Symbol	Parameter	Conditions		Min	Max	Unit
T _{stg}	storage temperature			-55	175	°C
T _j	junction temperature			-55	175	°C
Source-drain diode						
I _S	source current	T _{mb} = 25 °C		-	59	A
I _{SM}	peak source current	pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C		-	363	A
Avalanche ruggedness						
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I _D = 80 A; V _{sup} ≤ 40 V; R _{GS} = 50 Ω; V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped	[1] [2] [3]	-	58	mJ
I _{AS}	non-repetitive avalanche current	V _{sup} ≤ 40 V; V _{GS} = 10 V; T _{j(init)} = 25 °C; R _{GS} = 50 Ω; Fig. 4	[3]	-	80	A

- [1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
[2] Refer to application note AN10273 for further information.
[3] Protected by 100% test.



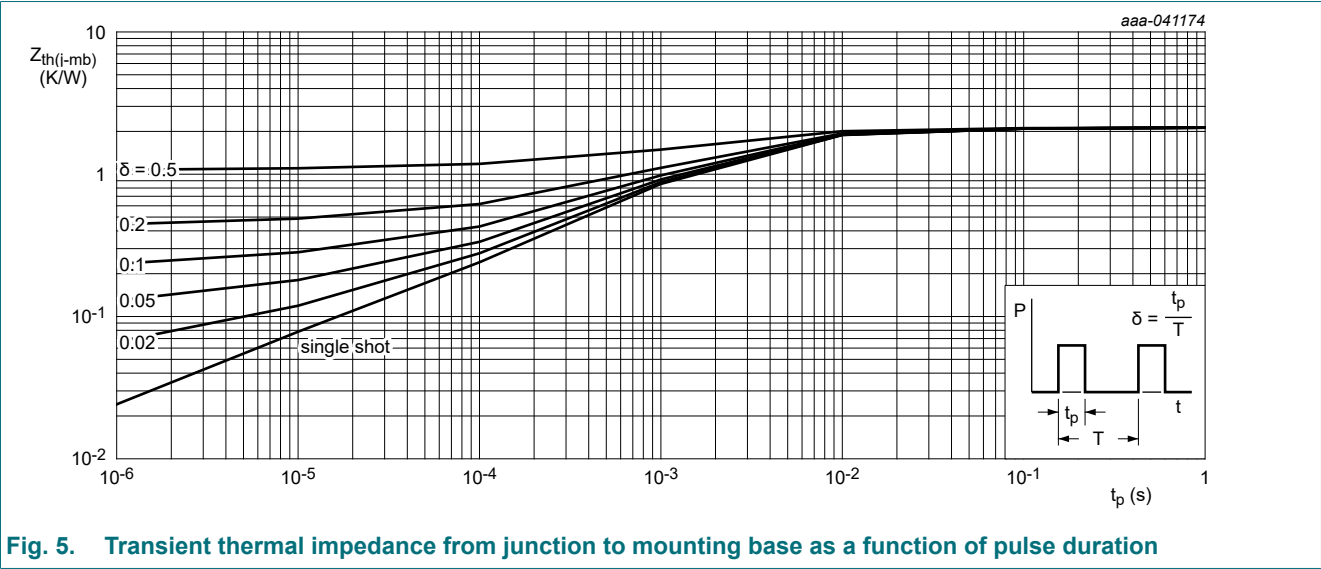


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	1.77	2.12	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1]	-	25	-	K/W

[1] Device on 4 layer PCB. Refer to TN00008 for further information.



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 µA; V _{GS} = 0 V; T _J = 25 °C		40	43	-	V
		I _D = 250 µA; V _{GS} = 0 V; T _J = -40 °C		-	40.5	-	V
		I _D = 250 µA; V _{GS} = 0 V; T _J = -55 °C		36	40	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _J = 25 °C; Fig. 9 ; Fig. 10		1.45	1.76	2.15	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _J = -55 °C; Fig. 10		-	-	2.6	V
		I _D = 1 mA; V _{DS} =V _{GS} ; T _J = 175 °C; Fig. 10		0.7	-	-	V
I _{DSS}	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _J = 25 °C		-	0.02	1	µA
		V _{DS} = 16 V; V _{GS} = 0 V; T _J = 125 °C		-	0.7	10	µA
		V _{DS} = 40 V; V _{GS} = 0 V; T _J = 175 °C		-	70	500	µA
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _J = 25 °C		-	2	100	nA
		V _{GS} = -20 V; V _{DS} = 0 V; T _J = 25 °C		-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _J = 25 °C; Fig. 11		2.7	3.8	4.5	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _J = 105 °C; Fig. 12		3.6	5.4	6.7	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _J = 125 °C; Fig. 12		3.9	5.9	7.3	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _J = 175 °C; Fig. 12		4.6	7	8.6	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _J = 25 °C; Fig. 11		3.2	4.6	5.9	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _J = 105 °C; Fig. 12		4.3	6.5	8.7	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _J = 125 °C; Fig. 12		4.7	7	9.5	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _J = 175 °C; Fig. 12		5.5	8.4	11.3	mΩ
R _G	gate resistance	f = 1 MHz; T _J = 25 °C		0.8	2	5.1	Ω
Dynamic characteristics							
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; T _J = 25 °C; Fig. 13 ; Fig. 14		-	36	50	nC
		I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; T _J = 25 °C; Fig. 13 ; Fig. 14		-	16	23	nC
Q _{GS}	gate-source charge			-	6.6	10	nC
Q _{GD}	gate-drain charge			-	3.7	7.4	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _J = 25 °C; Fig. 15		-	2512	3517	pF
C _{oss}	output capacitance			-	437	612	pF
C _{rss}	reverse transfer capacitance			-	100	220	pF
t _{d(on)}	turn-on delay time	V _{DS} = 20 V; R _L = 0.8 Ω; V _{GS} = 4.5 V; R _{G(ext)} = 5 Ω; T _J = 25 °C		-	16	-	ns
t _r	rise time			-	24	-	ns
t _{d(off)}	turn-off delay time			-	22	-	ns

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
t _f	fall time			-	14	-	ns
Source-drain diode							
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; Fig. 16		-	0.83	1.2	V
t _{rr}	reverse recovery time	I _S = 25 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V;	[1]	-	23	-	ns
Q _r	recovered charge	V _{DS} = 20 V; T _j = 25 °C; Fig. 17		-	14	-	nC

[1] includes capacitive recovery

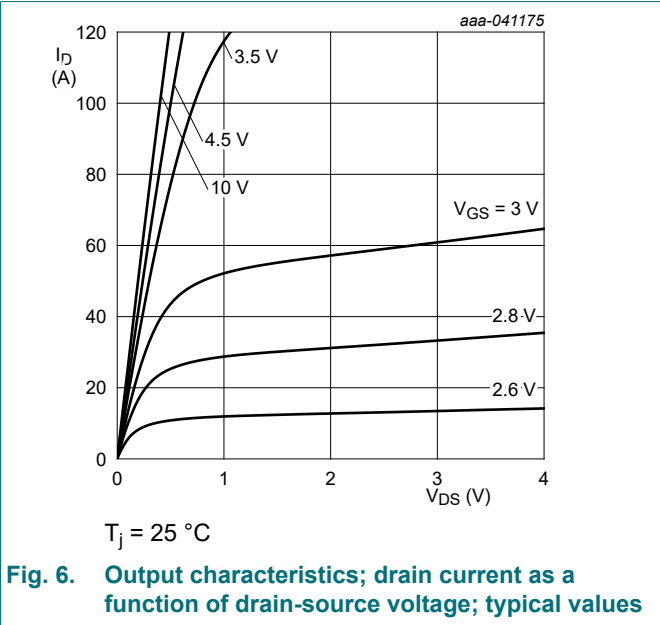


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

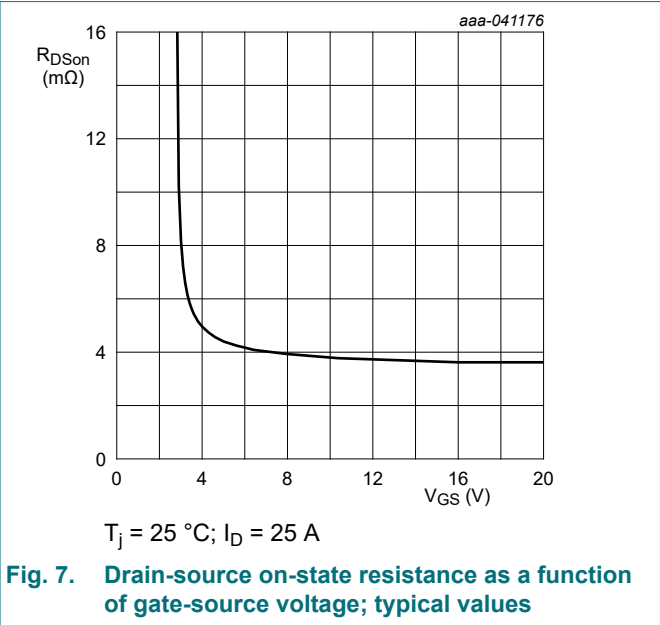


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

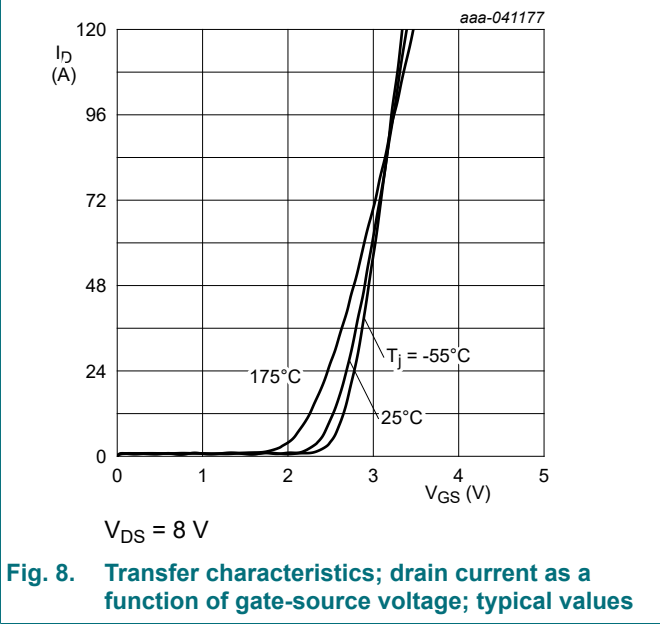


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

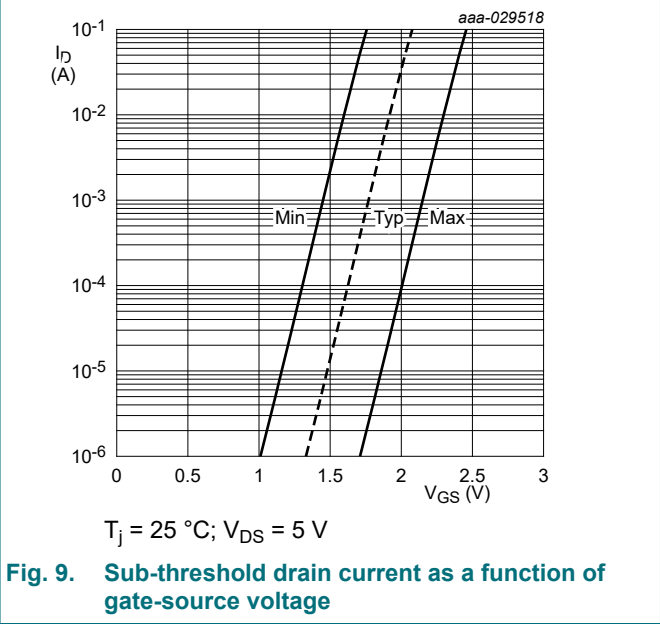


Fig. 9. Sub-threshold drain current as a function of gate-source voltage

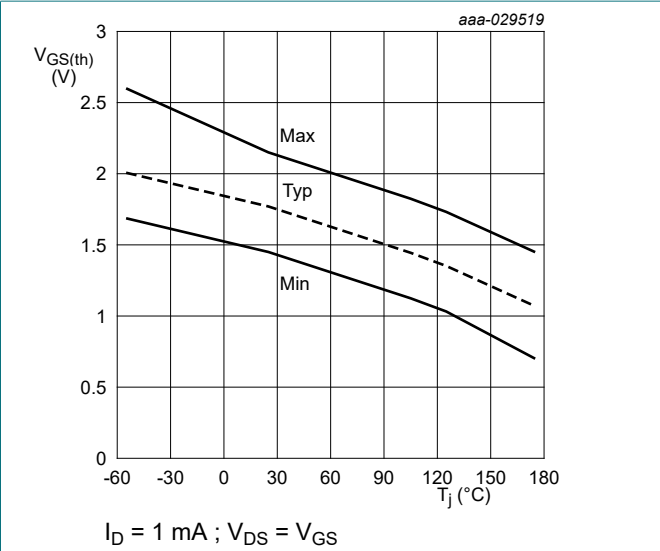


Fig. 10. Gate-source threshold voltage as a function of junction temperature

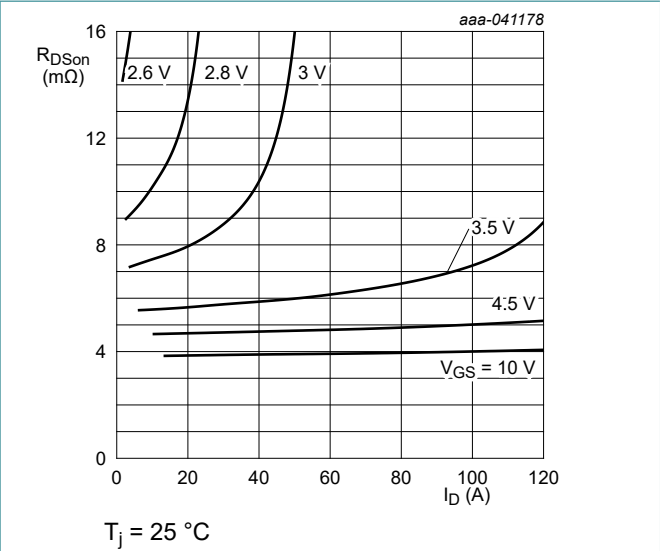


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

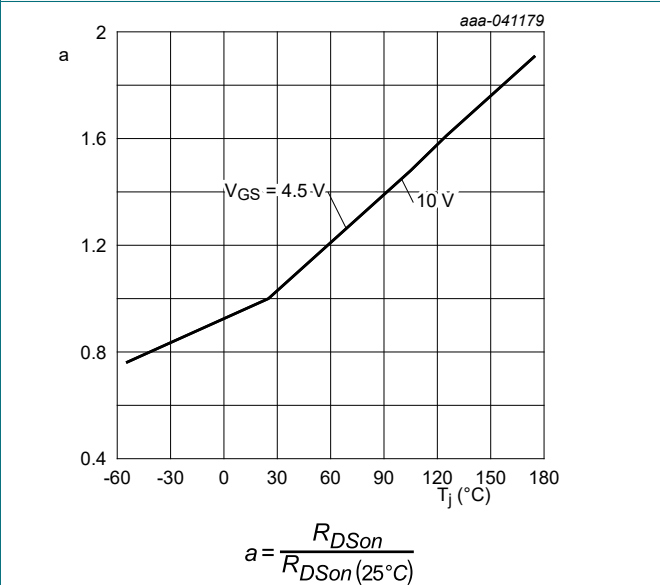


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

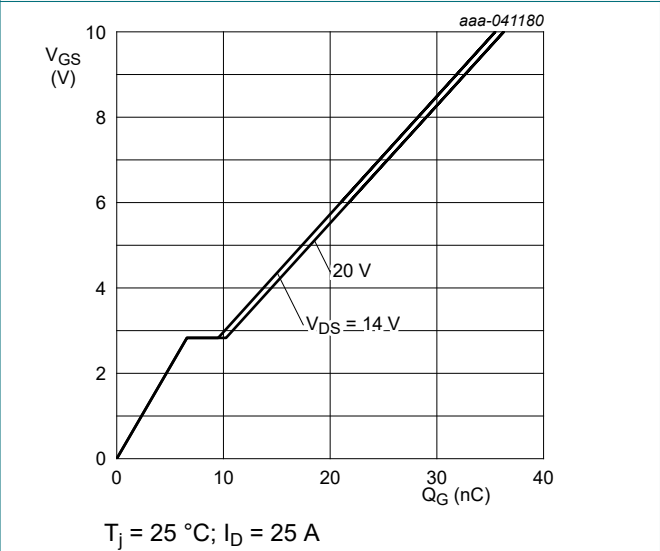


Fig. 13. Gate-source voltage as a function of gate charge; typical values

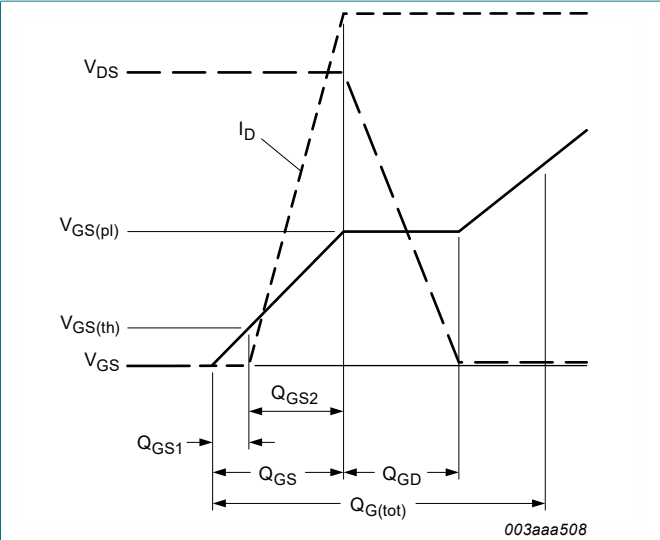


Fig. 14. Gate charge waveform definitions

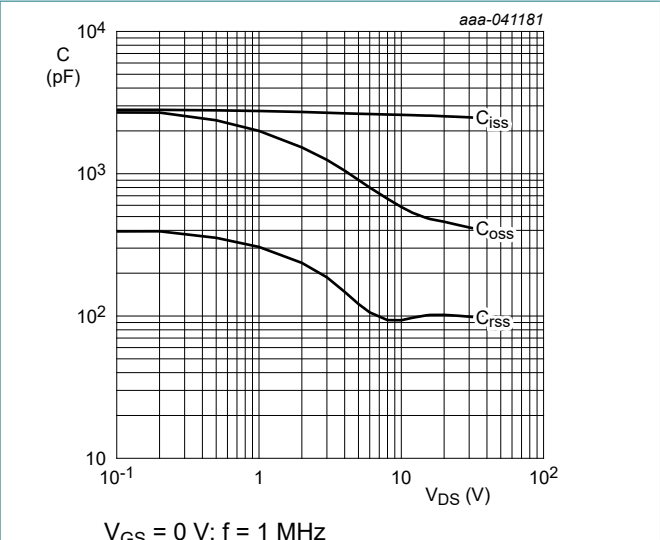


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

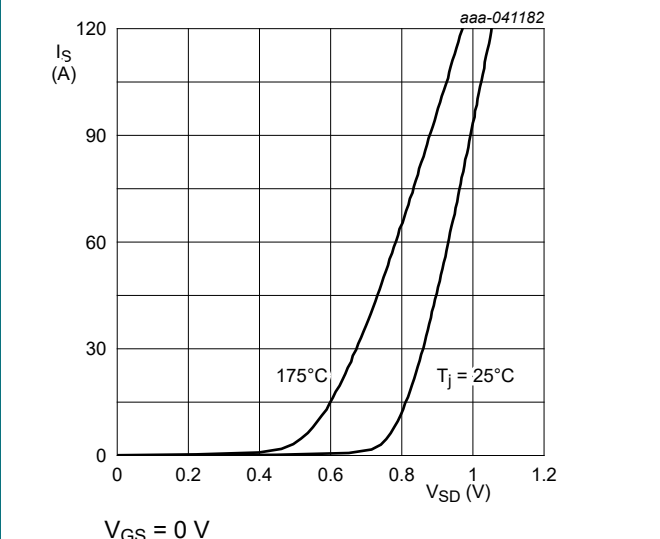


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

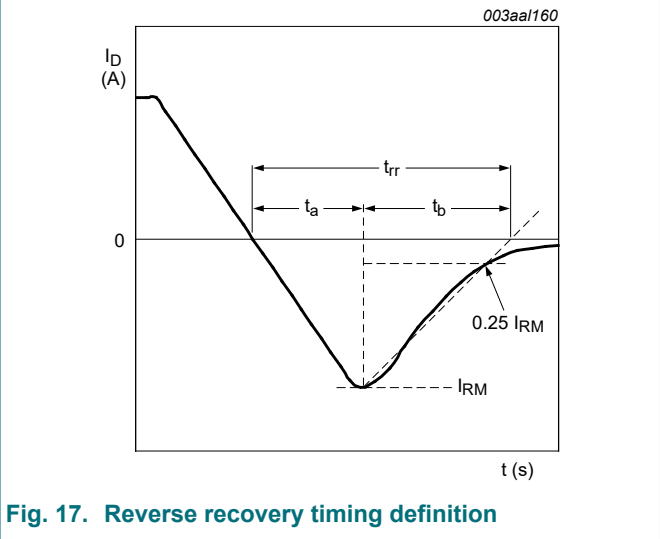


Fig. 17. Reverse recovery timing definition

11. Package outline

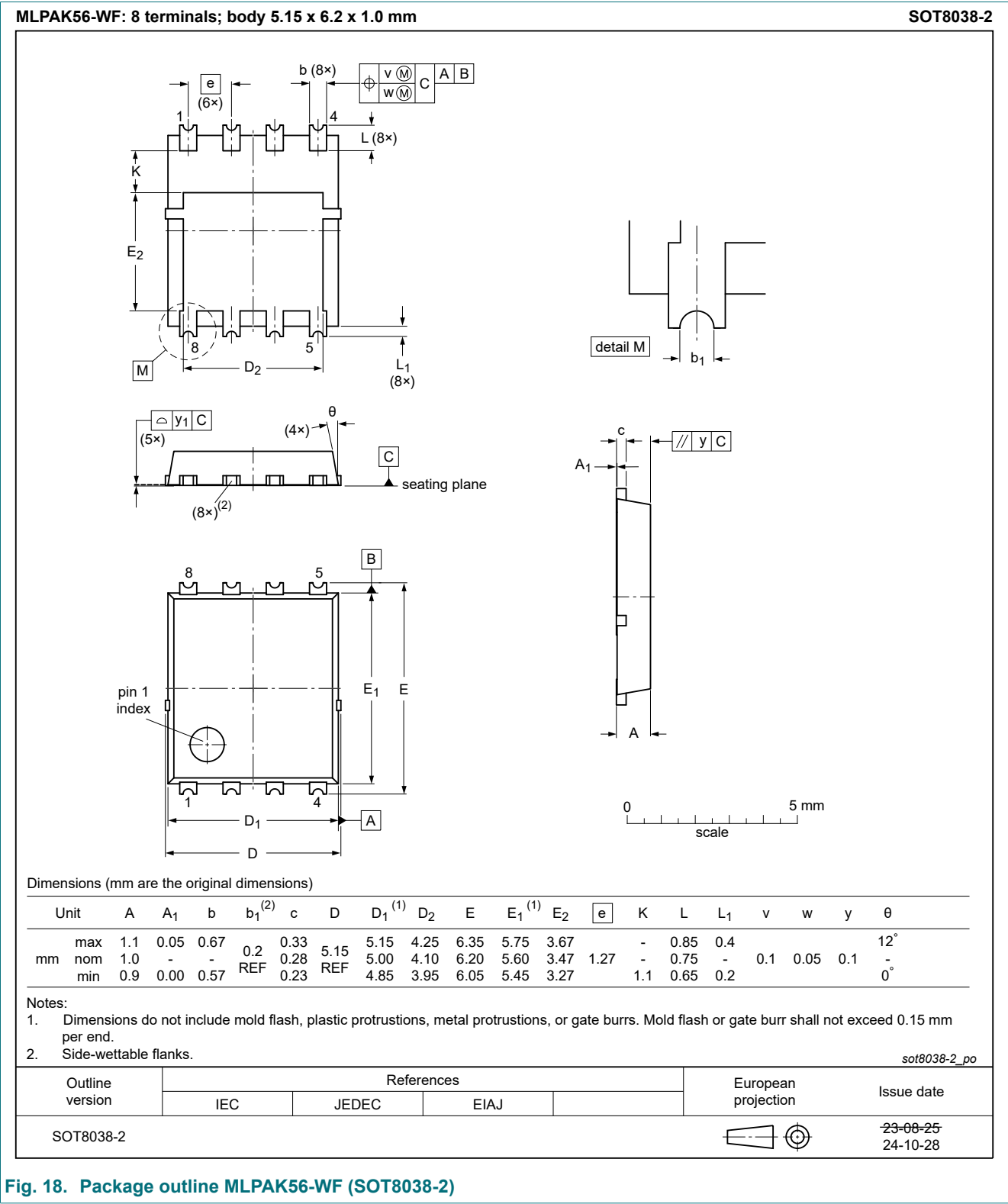


Fig. 18. Package outline MLPAK56-WF (SOT8038-2)

13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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